

# Step Down DC - DC Converter Power IC

## MD3221R

Small footprint

Output adjustable

Remote On/Off

Synchronous Rectification

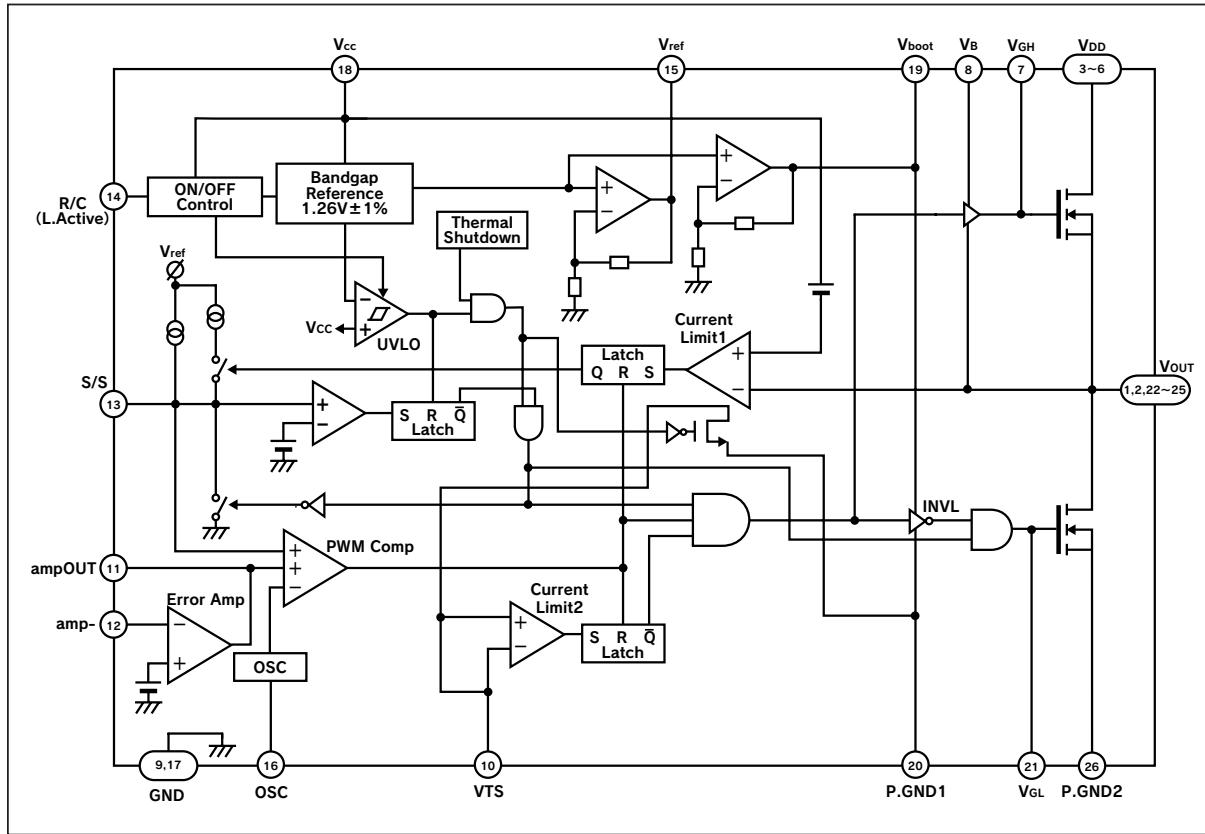
5V Input

### Feature

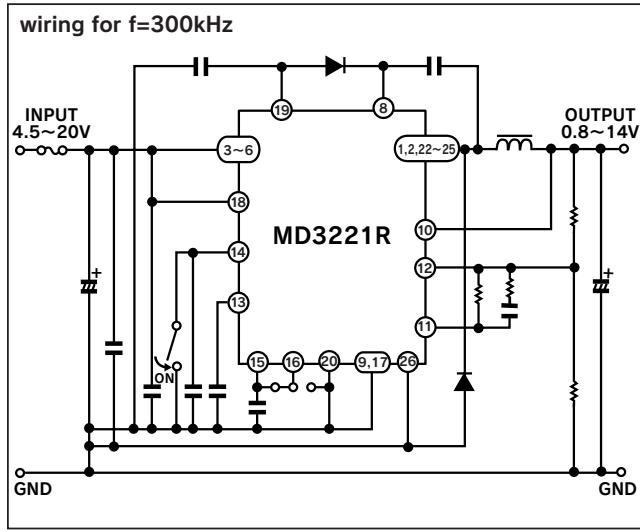
- Input Voltage range 4.5V to 20V
- Maximum Output Current 3A
- Built-in MOSFETs for main switch and synchronous rectification
- Adjustable output from 0.8V to 14V with external resistors
- High Efficiency typ. 96% (at Vin=5V, Vout=3.3V, Iout=1A, f=100kHz)
- 100kHz / 300kHz selectable switching frequency

- Over Current Protection
  - Under Voltage Lockout
  - Thermal Shut Down
  - Remote On / Off
- Supply current at remote off 25 $\mu$ A typ.

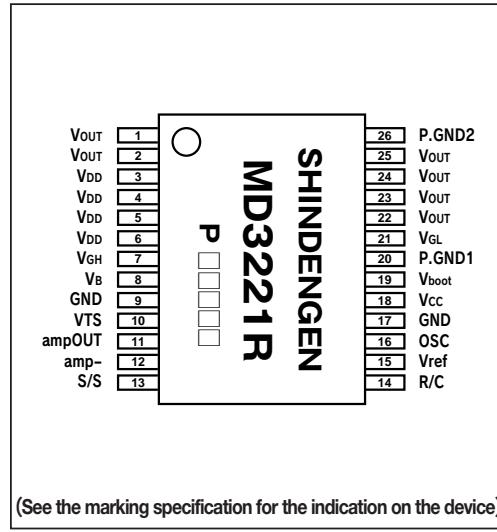
### Block Diagram



### Standard Connection Diagram



### Pin Assignment (LSSOP26)



## Absolute Maximum Ratings

Unless otherwise specified : Ta=25°C

Item	Symbol	Ratings	Units
Input/Output Ratings			
Input voltage	V <sub>CC</sub>	22	V
Main MOSFET input voltage	V <sub>D</sub>	22	V
Output current (ave)	I <sub>OUTave</sub>	3	A
Output current (peak)	I <sub>OUTpeak</sub>	4	A
Input voltage between V <sub>B</sub> and V <sub>OUT</sub>	V <sub>B</sub>	5.5	V
Vboot sink current	I <sub>boot</sub>	-30	mA
Remote control voltage	V <sub>RC</sub>	V <sub>CC</sub>	V
OSC input voltage	V <sub>OSC</sub>	V <sub>ref</sub>	V
Amp- input voltage	V <sub>Amp-</sub>	V <sub>ref</sub>	V
V <sub>ref</sub> sink current	I <sub>ref</sub>	-3	mA
Thermal Ratings			
Power dissipation max <sup>※1</sup>	PD1 <sup>※3</sup>	1.1	W
	PD2 <sup>※3</sup>	1.5	W
Operating temperature	T <sub>a-ope</sub>	-30 to 85	°C
Storage temperature	T <sub>stg</sub>	-40 to 150	°C
Junction temperature	T <sub>j</sub>	150	°C
Thermal resistance <sup>※1</sup>	θ <sub>ja1</sub> <sup>※3</sup>	110	°C/W
	θ <sub>ja2</sub> <sup>※3</sup>	87	°C/W
	θ <sub>jc1</sub> <sup>※2,※3</sup>	55	°C/W
	θ <sub>jc2</sub> <sup>※2,※3</sup>	30	°C/W

<sup>※1</sup> CEM-3 Board : 50.8×50.8mm<sup>2</sup>, Thickness : 1mm, Copper Pattern : 300mm<sup>2</sup> (Top Side), There is no through-hole. <sup>※2</sup> The measurement result in the center of case.<sup>※3</sup> PD1, θ<sub>ja1</sub>, θ<sub>jc1</sub> are the values of the power dissipation and thermal resistance when electrifying to a single internal element.PD2, θ<sub>ja2</sub>, θ<sub>jc2</sub> are the values of the power dissipation and thermal resistance when electrifying to two internal element.

## Recommended Operating Conditions

Item	Symbol	Recommendation	Units
Junction temperature	T <sub>j</sub>	-30 to 125	°C
Input voltage	V <sub>i</sub> <sup>※4</sup>	4.5 to 20	V
Output voltage setting range	V <sub>O</sub> <sup>※5</sup>	0.8 to 14	V

<sup>※4</sup> Input voltage at the time of power supply operation.<sup>※5</sup> Output voltage at the time of power supply operation.

## Electrical Characteristics

Unless otherwise specified : Ta=25°C

Item	Symbol	Condition	MIN	TYP	MAX	Units
High Side MOSFET						
Drain-source breakdown voltage	V <sub>DSS_H</sub>	ID=1mA, V <sub>GS</sub> =0V	22	—	—	V
Zero gate voltage drain current	I <sub>DSS_H</sub>	V <sub>D</sub> =22V, V <sub>GS</sub> =0V	—	—	10	μA
Static drain-source on-state resistance	R <sub>ON_H</sub>	ID=1.2A, V <sub>GS</sub> =4.5V	—	22	55	mΩ
Source-drain diode forward voltage	V <sub>SD_H</sub>	IS=1.2A, V <sub>GS</sub> =0V	—	—	1.5	V
Low Side MOSFET						
Drain-source breakdown voltage	V <sub>DSS_L</sub>	ID=1mA, V <sub>GS</sub> =0V	22	—	—	V
Zero gate voltage drain current	I <sub>DSS_L</sub>	V <sub>D</sub> =22V, V <sub>GS</sub> =0V	—	—	10	μA
Static drain-source on-state resistance	R <sub>ON_L</sub>	ID=1.2A, V <sub>GS</sub> =4.5V	—	22	55	mΩ
Source-drain diode forward voltage	V <sub>SD_L</sub>	IS=1.2A, V <sub>GS</sub> =0V	—	—	1.5	V
Control IC						
Supply current (f=100kHz)	I <sub>CC_L</sub>	V <sub>CC</sub> =4.5V to 20V	—	3.3	3.9	mA
Supply current (f=300kHz)	I <sub>CC_H</sub>	V <sub>CC</sub> =4.5V to 20V	—	5	5.9	mA
Supply current at remote OFF	I <sub>CC_off</sub>	V <sub>CC</sub> =4.5V to 20V	—	25	50	μA
Undervoltage lockout threshold (start)	V <sub>CC_start</sub>	—	4.1	4.3	4.5	V
Undervoltage lockout hysteresis	V <sub>CC_hys</sub>	—	0.4	0.5	0.6	V
Bootstrap voltage	V <sub>boot</sub>	V <sub>CC</sub> =5V	3.84	4	4.16	V
Line regulation	V <sub>B-IN</sub>	V <sub>CC</sub> =4.5V to 20V	—	—	30	mV
Load regulation	V <sub>B-L</sub>	V <sub>CC</sub> =5V	—	—	30	mV
Reference voltage	V <sub>ref</sub>	V <sub>CC</sub> =5V	3.84	4	4.16	V
Line regulation	REG-IN	V <sub>CC</sub> =4.5V to 20V	—	—	30	mV
Load regulation	REG-L	V <sub>CC</sub> =5V	—	—	30	mV
Initial frequency1 accuracy	f <sub>osc_1</sub>	V <sub>CC</sub> =5V	85	100	115	kHz
Initial frequency2 accuracy	f <sub>osc_2</sub>	V <sub>CC</sub> =5V	255	300	345	kHz
Maximum duty cycle	D <sub>TY_max</sub>	V <sub>CC</sub> =5V	85	90	95	%
Remote control ON input voltage	V <sub>R/C_ON</sub>	V <sub>CC</sub> =5V	-0.2	—	0.7	V
Remote control OFF input voltage	V <sub>R/C_OFF</sub>	V <sub>CC</sub> =5V	2	—	V <sub>CC</sub>	V
Remote control source current	I <sub>RC</sub>	V <sub>CC</sub> =5V	—	2	10	μA
Soft-start source current	I <sub>s/s</sub>	V <sub>CC</sub> =5V	-3	-2.5	-2	μA
Error amplifier reference voltage	V <sub>Amp</sub>	V <sub>CC</sub> =5V	0.784	0.8	0.816	V
Threshold of over current limit at Ron detection	I <sub>th_OCL1</sub>	V <sub>CC</sub> =5V	3	—	—	A
Timer current	I <sub>timer</sub>	V <sub>CC</sub> =5V	-40	-33	-26	μA
Soft-start input voltage before timer starting	V <sub>s/s</sub>	V <sub>CC</sub> =5V	2.75	2.9	3.05	V
Threshold of latch	V <sub>th_lat</sub>	V <sub>CC</sub> =5V	3.3	3.45	3.6	V
Output voltage accuracy (V <sub>O</sub> =0.8V)	V <sub>F/B_1</sub>	V <sub>CC</sub> =4.5V to 20V	0.784	0.800	0.816	V
Thermal shutdown temperature	T <sub>TSD</sub>	—	—	140	—	°C